BTA212B series C

GENERAL DESCRIPTION

Glass passivated high commutation triacs in a plastic envelope suitable for surface mounting intended for use in circuits where high static and dynamic dV/dt and high dl/dt can occur. These devices will commutate the full rated rms current at the maximum rated junction temperature, without the aid of a snubber.

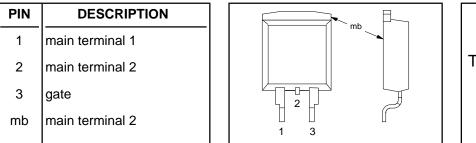
PINNING - SOT404

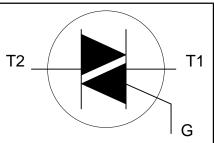
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
V _{DRM} I _{T(RMS)} I _{TSM}	BTA212B- Repetitive peak off-state voltages RMS on-state current Non-repetitive peak on-state current	500C 500 12 95	600C 600 12 95	800C 800 12 95	V A A

PIN CONFIGURATION

SYMBOL





LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.			UNIT
V _{DRM}	Repetitive peak off-state voltages		-	-500 500 ¹	-600 600 ¹	-800 800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 99 °C	-		12		A
I _{TSM}	Non-repetitive peak on-state current	full sine wave; $T_j = 25 \degree C$ prior to surge $t = 20 \ ms$ $t = 16.7 \ ms$	-		95 105		A
l²t dl _⊤ /dt	I ² t for fusing Repetitive rate of rise of on-state current after triggering	t = 10.7 ms t = 10 ms $I_{TM} = 20 \text{ A}; I_G = 0.2 \text{ A};$ $dI_G/dt = 0.2 \text{ A}/\mu \text{s}$	-		45 100		Α A²s A/μs
I _{GM} V _{GM} P _{GM} P _{G(AV)}	Peak gate current Peak gate voltage Peak gate power Average gate power	over any 20 ms period			2 5 5 0.5		A V W W
T _{stg} T _j	Storage temperature Operating junction temperature	penou	-40 -		150 125		°℃ ℃

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15 $A/\mu s$.

BTA212B series C

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb} R _{th j-a}	Thermal resistance junction to mounting base Thermal resistance junction to ambient	full cycle half cycle in free air		- - 60	1.5 2.0 -	K/W K/W K/W

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS		MIN.	TYP.	MAX.	UNIT
I _{GT}	Gate trigger current ²	$V_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$					
01			T2+ G+	2	-	35	mA
			T2+ G-	2	-	35	mA
			T2- G-	2	-	35	mA
I _L	Latching current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$					
	-		T2+ G+	-	-	20	mA
			T2+ G-	-	-	30	mA
			T2- G-	-	-	20	mA
I _H	Holding current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$		-	-	15	mA
I _H V _T V _{GT}	On-state voltage	$I_{T} = 17 \text{ A}$		-	1.3	1.6	V
V _{GT}	Gate trigger voltage	$V_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$		-	0.7	1.5	V
		$V_{\rm D} = 400 \text{ V}; I_{\rm T} = 0.1 \text{ A}; T_{\rm i} = 125$	°C	0.25	0.4	-	V
I _D	Off-state leakage current	$V_{\rm D}^{\rm B} = V_{\rm DRM(max)}; T_{\rm j} = 125 \ ^{\circ}{\rm C}$		-	0.1	0.5	mA

DYNAMIC CHARACTERISTICS

 $T_j = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	UNIT
dV _D /dt	Critical rate of rise of off-state voltage	$V_{DM} = 67\% V_{DRM(max)}$; $T_j = 125$ °C; exponential waveform; gate open circuit	1000	-	V/µs
dl _{com} /dt	Critical rate of change of commutating current	$V_{DM} = 400 \text{ V}; T_j = 125 \text{ °C}; I_{T(RMS)} = 12 \text{ A}; without snubber; gate open circuit$	3	14	A/ms
t _{gt}	Gate controlled turn-on time	$I_{TM} = 12 \text{ A}; V_D = V_{DRM(max)}; I_G = 0.1 \text{ A};$ $dI_G/dt = 5 \text{ A}/\mu \text{s}$	-	2	μs

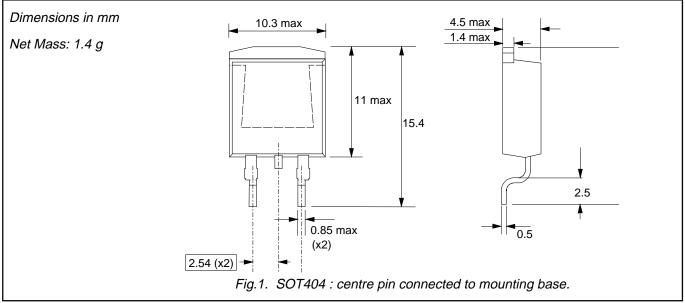
Downloaded from Elcodis.com electronic components distributor

² Device does not trigger in the T2-, G+ quadrant.

Preliminary specification

BTA212B series C

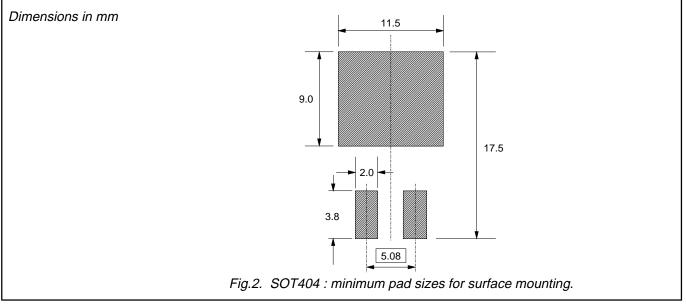
MECHANICAL DATA



Notes

1. Epoxy meets UL94 V0 at 1/8".

MOUNTING INSTRUCTIONS



Notes

1. Plastic meets UL94 V0 at 1/8".

BTA212B series C

DEFINITIONS

Data sheet status				
Objective specification	This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	pecification This data sheet contains final product specifications.			
Limiting values				
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.				
Application information				
Where application inform	ation is given, it is advisory and does not form part of the specification.			
© Philips Electronics N	.V. 1997			
All rights are recorded. Depreduction in whole or in part is prohibited without the prior written concert of the				

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, it is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent or other industrial or intellectual property rights.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.